

Sample &

Buy





TMP708

SBOS585B - DECEMBER 2011 - REVISED DECEMBER 2016

TMP708 Resistor-Programmable Temperature Switch in SOT Package

Technical

Documents

1 Features

- Threshold Accuracy:
 - ±0.5°C Typical
 - ±3°C Maximum (60°C to 100°C)
- Temperature Threshold Set By 1% External Resistor
- Low Quiescent Current: 40 μA, Typical
- Open-Drain, Active-Low Output Stage
- Pin-Selectable 10°C or 30°C Hysteresis
- Reset Operation Specified at V_{CC} = 0.8 V
- Supply Range: 2.7 V to 5.5 V
- Package: 5-Pin SOT-23

2 Applications

- Computers (Laptops and Desktops)
- Servers
- Industrial and Medical Equipment
- Storage Area Networks
- Automotive

3 Description

Tools &

Software

The TMP708 is a fully-integrated, resistorprogrammable temperature switch with a temperature threshold that is set by just one external resistor within the entire operating range. The TMP708 provides an open-drain, active-low output and has a 2.7-V to 5.5-V supply voltage range.

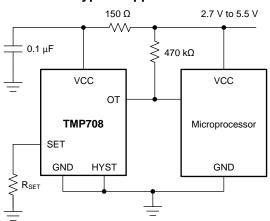
The temperature threshold accuracy is typically $\pm 0.5^{\circ}$ C, with a maximum of $\pm 3^{\circ}$ C (60°C to 100°C). The quiescent current consumption is typically 40 μ A. Hysteresis is pin-selectable to 10°C or 30°C.

The TMP708 is available in a 5-pin, SOT-23 package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TMP708	SOT-23 (5)	2.90 mm x 1.60 mm

(1) For all available packages, see the package option addendum at the end of the datasheet.



Copyright © 2016, Texas Instruments Incorporated

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

Typical Application

Table of Contents

1	Features 1									
2	Арр	Applications 1								
3	Description 1									
4	Rev	ision History 2								
5	Pin	Configuration and Functions 3								
6	Spe	cifications 4								
	6.1	Absolute Maximum Ratings 4								
	6.2	ESD Ratings 4								
	6.3	Recommended Operating Conditions 4								
	6.4	Thermal Information 4								
	6.5	Electrical Characteristics 5								
	6.6	Typical Characteristics 6								
7	Deta	ailed Description7								
	7.1	Overview								
	7.2	Functional Block Diagram 7								
	7.3	Feature Description8								

	7.4	Device Functional Modes	8
8	App	lication and Implementation	9
	8.1	Application Information	9
	8.2	Typical Application	9
9	Pow	er Supply Recommendations1	1
10	Lay	out1	1
	10.1	Layout Guidelines 1	1
	10.2	Layout Example 1	1
	10.3	Thermal Considerations 1	1
11	Dev	ice and Documentation Support 12	2
	11.1	Receiving Notification of Documentation Updates 1	2
	11.2	Community Resources1	2
	11.3	Trademarks 1	2
	11.4	Electrostatic Discharge Caution 1	2
	11.5	Glossary1	2
12		hanical, Packaging, and Orderable mation	2

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (February 2012) to Revision B

•	Description, Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable Information sections Deleted Package and Ordering Information table; information now available in package option addendum located at	1
	the end of this data sheet	Page

Changes from Original (December 2011) to Revision A

•	Updated threshold accuracy feature bullet	1
•	Updated threshold accuracy text in second paragraph of <i>Description</i> section	1
•	Updated temperature error parameter in the Electrical Characteristics	5

2



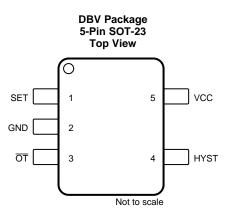
www.ti.com

Page



TMP708 SBOS585B – DECEMBER 2011 – REVISED DECEMBER 2016

5 Pin Configuration and Functions



Pin Functions

PIN		ТҮРЕ	DESCRIPTION		
NAME	NO.	1175	DESCRIPTION		
GND	2	Analog power	Device ground		
HYST	4	Digital input	Hysteresis selection. For 10°C, HYST = VCC; for 30°C, HYST = GND.		
OT	3	Digital output	Open-drain, active low output		
SET	1	Analog input	Temperature set point. Connect an external 1% resistor between SET and GND.		
VCC 5 Analog power		Analog power	Power-supply voltage (2.7 V to 5.5 V)		

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Voltage	Supply, VCC	-0.3	6	
	Input, SET and HYST	-0.3	$V_{CC} + 0.3$	V
	Output, OT	-0.3	6	
Current	Input		20	
	Output		20	mA
Temperature	Operating, T _A	-40	125	
	Junction, T _J		150	°C
	Storatge, T _{stg}	-65	150	

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electr		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	
	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V
		Machine model (MM)	±200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V _{CC}	Supply voltage	2.7	5.5	V
T _A	Operating temperature	0	125	°C

6.4 Thermal Information

		TMP708	
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	UNIT
		5 PINS	
$R_{ hetaJA}$	Junction-to-ambient thermal resistance	217.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	86.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.6	°C/W
ΨJT	Junction-to-top characterization parameter	4.4	°C/W
Ψјв	Junction-to-board characterization parameter	43.8	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



6.5 Electrical Characteristics

at T_{A} = 0°C to 125°C and V_{CC} = 2.7 V to 5.5 V (unless otherwise noted)

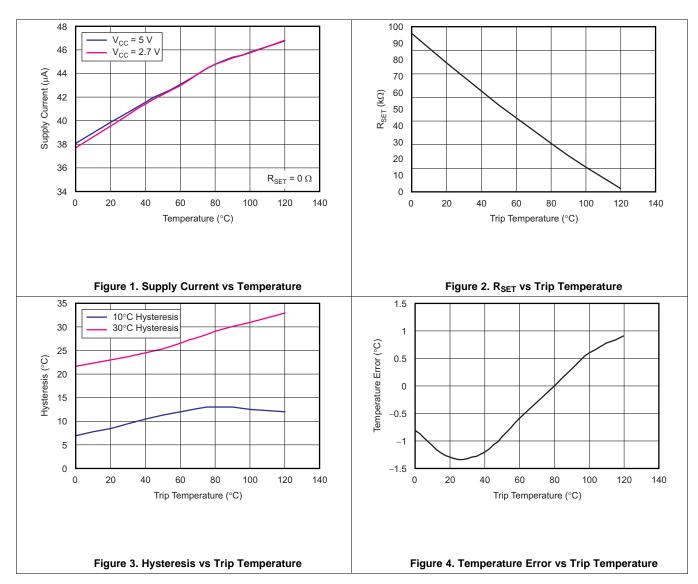
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
POWER S	UPPLY							
	Supply ourrent	$V_{CC} = 5 V$		40	55	μA		
I _{CC}	Supply current	V _{CC} = 2.7 V		40	55	μA		
TEMPERATURE								
Τ _Ε	Temperature error	$T_A = 60^{\circ}C$ to $100^{\circ}C$		±0.5	±3	°C		
DIGITAL II	NPUT (HYST)							
V _{IH}	High-level input voltage		0.7 × V _{CC}			V		
V _{IL}	Low-level input voltage				$0.3 \times V_{CC}$	V		
l _{lkg_in}	Input leakage current			1		μA		
C _{IN}	Input capacitance			10		pF		
ANALOG	NPUT (SET)							
V _{IN}	Input voltage range		0		V _{CC}	V		
DIGITAL C	PEN-DRAIN OUTPUT (OT)							
I(OT_SINK)	Output sink current	V _{OT} = 0.3 V	5	12		mA		
I _{lkg(OT)}	Output leakage current	V _{OT} = V _{CC}		1		μA		



TMP708 SBOS585B – DECEMBER 2011 – REVISED DECEMBER 2016

6.6 Typical Characteristics

at $T_A = 25^{\circ}C$ and $V_{CC} = 2.7$ V to 5.5 V (unless otherwise noted)





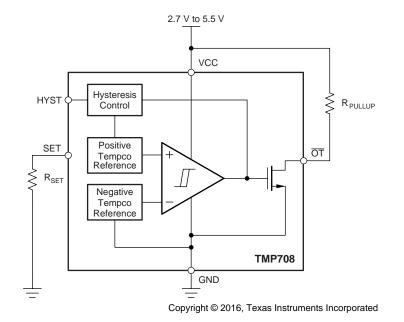
7 Detailed Description

7.1 Overview

The TMP708 is a fully-integrated, resistor-programmable temperature switch that incorporates two temperature dependent voltage references and one comparator. One voltage reference exhibits a positive temperature coefficient (tempco), and the other voltage reference exhibits a negative tempco. The temperature at which both voltage references are equal determines the temperature trip point.

The Functional Block Diagram shows the comparator, the NFET open-drain device connected to the \overline{OT} pin, the positive tempco reference using the external R_{SET} resistor, the negative tempco reference, and the hysteresis control. The voltage of the positive tempco reference is controlled by external resistor R_{SET}.

7.2 Functional Block Diagram





(1)

7.3 Feature Description

7.3.1 Temperature Switch

The TMP708 temperature threshold is programmable from 0°C to 125°C and is set by an external 1% resistor from the SET pin to the GND pin. The TMP708 has an open-drain, active-low output structure that easily interfaces with a microprocessor.

The TMP708 reaches the temperature trip point when the voltage from the positive tempco reference exceeds the voltage from the negative tempco reference. This difference causes the output of the comparator to switch from logic 0 to logic 1. The comparator output drives the gate of the NFET open-drain device, and pulls the voltage on the OT pin from logic 1 to logic 0 under these conditions; in other words, the output *trips*. Furthermore, the logic 1 output from the comparator causes the hysteresis control to increase the voltage of the PST pin; 30°C for logic 0 on the HYST pin). Increase the voltage of the positive tempco reference after the TMP708 trips to stop the TMP708 from untripping (voltage on the OT pin changing from logic 0 to logic 1) until the local temperature reduces by the amount set by the HYST pin. After the local temperature reduces, and the voltage from the positive tempco reference is less than the voltage from the negative tempco reference, the output of the comparator switches from logic 1 to logic 0. This condition causes the voltage on the OT pin to change from logic 0 to logic 1 to logic 1 to logic 0. This condition causes the voltage on the OT pin to change from logic 0 to logic 1 to logic 1 to logic 0. This condition causes the voltage on the OT pin to change from logic 0 to logic 1 (device untrips).

7.3.2 Hysteresis Input

The HYST pin is a digital input that allows the input hysteresis to be set at either $10^{\circ}C$ (when HYST = VCC) or $30^{\circ}C$ (when HYST = GND). The hysteresis function keeps the OT pin from oscillating when the temperature is near the threshold. Thus, always connect the HYST pin to either VCC or GND. Other input voltages on this pin can cause abnormal supply currents or a device malfunction.

7.3.3 Set-Point Resistor (R_{SET})

Set the temperature threshold by connecting R_{SET} from the SET pin to GND. The value of R_{SET} is determined using either Figure 2 or Equation 1:

 R_{SET} (k Ω) = 0.0012T² - 0.9308T + 96.147

where

T = temperature threshold in degrees Celsius.

7.4 Device Functional Modes

The TMP708 device has a single functional mode. Normal operation for the TMP708 device occurs when the power-supply voltage applied across the VCC and GND pins is within the specified operating range of 2.7 V to 5.5 V.

8



TMP708 SBOS585B – DECEMBER 2011 – REVISED DECEMBER 2016

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TMP708 device is simple to configure. The only external components that the device requires are a bypass capacitor and pullup resistor. Power-supply bypassing is strongly recommended. Use a 0.1- μ F capacitor placed as close as possible to the VCC supply pin. To minimize the internal power dissipation of the TMP708 family of devices, use a pullup resistor value greater than 10 k Ω from the \overline{OT} pin to the VCC pin. See the *Hysteresis Input* section for hysteresis configuration, and the *Set-Point Resistor* (R_{SET}) section for configuring the temperature threshold.

8.2 Typical Application

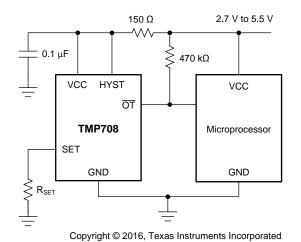


Figure 5. Overtemperature Protection for a 60°C Trip Point

8.2.1 Design Requirements

For this design example, a 2.7-V to 5.5-V power supply, 60°C trip point, and 10°C hysteresis are used.



Typical Application (continued)

8.2.2 Detailed Design Procedure

Connect the HYST pin to VCC for 10°C hysteresis. For a 60°C temperature threshold, see the *Set-Point Resistor* (R_{SET}) section to compute an ideal R_{SET} resistor value of 44.619 k Ω . Select the closest standard value resistor available; in this case, 44.2 k Ω . Use a 10-k Ω pullup resistor from the OT pin to the VCC pin. To minimize power, a larger-value pullup resistor can be used, but must not exceed 470 k Ω . Place a 0.1- μ F bypass capacitor close to the TMP708 device in order to reduce noise coupled from the power supply.

8.2.3 Application Curves

Figure 6 shows an example of the hysteresis feature. The HYST pin is connected to VCC, so the TMP708 device is configured for 10° C of hysteresis. The device is configured for a 60°C trip temperature by the R_{SET} resistor value; therefore, the OT output asserts low when the 60°C threshold is exceeded. The OT output remains asserted low until the sensor reaches 50°C.

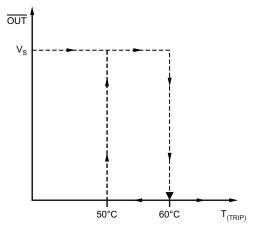


Figure 6. TMP708 Hysteresis Function



9 Power Supply Recommendations

The TMP708 low supply current and supply range allow this device to be powered from many sources. Any significant noise on the VCC pin can result in a trip-point error. Minimize this noise by low-pass filtering the device supply (V_{CC}) using a 150- Ω resistor and a 0.1- μ F capacitor.

10 Layout

10.1 Layout Guidelines

The TMP708 is extremely simple to lay out. Figure 7 shows the recommended board layout.

10.2 Layout Example

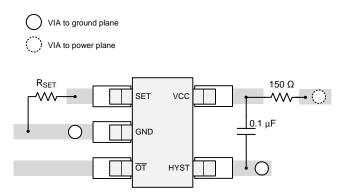


Figure 7. Recommended Layout

10.3 Thermal Considerations

The TMP708 quiescent current is typically 40 μ A. The device dissipates negligible power when the output drives a high-impedance load. Thus, the die temperature is the same as the package temperature. In order to maintain accurate temperature monitoring, provide a good thermal contact between the TMP708 package and the device being monitored. The rise in die temperature as a result of self-heating is given by Equation 2:

$$\Delta T_{J} = P_{DISS} \times \theta_{JA}$$

where

- P_{DISS} = power dissipated by the device.
 - θ_{JA} = package thermal resistance. Typical thermal resistance for SOT-23 package is 217.9°C/W. (2)

To limit the effects of self-heating, keep the output current at a minimum level.

FXAS NSTRUMENTS

www.ti.com

Device and Documentation Support 11

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

Electrostatic Discharge Caution 11.4



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.



ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

Mechanical, Packaging, and Orderable Information 12

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
TMP708AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SBI
TMP708AIDBVR.Z	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SBI
TMP708AIDBVRG4.Z	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TMP708AIDBVT	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	SBI

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TMP708 :

Downloaded from Arrow.com.



14-May-2025

Automotive : TMP708-Q1

NOTE: Qualified Version Definitions:

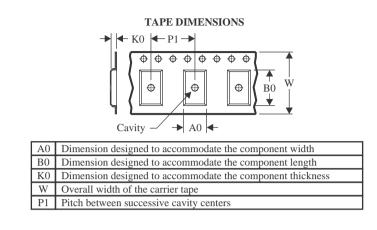
• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects





TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nom	inal
-------------------------	------

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMP708AIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



PACKAGE MATERIALS INFORMATION

30-Mar-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMP708AIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0

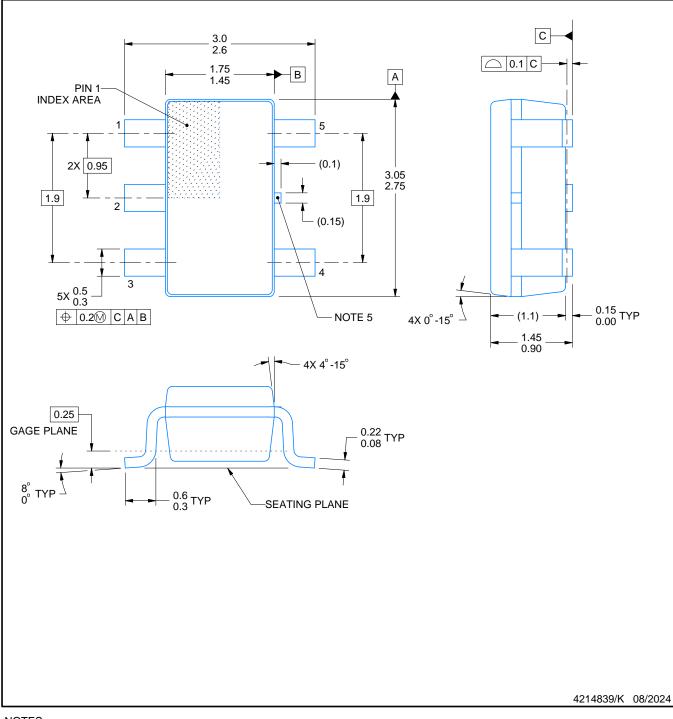
DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

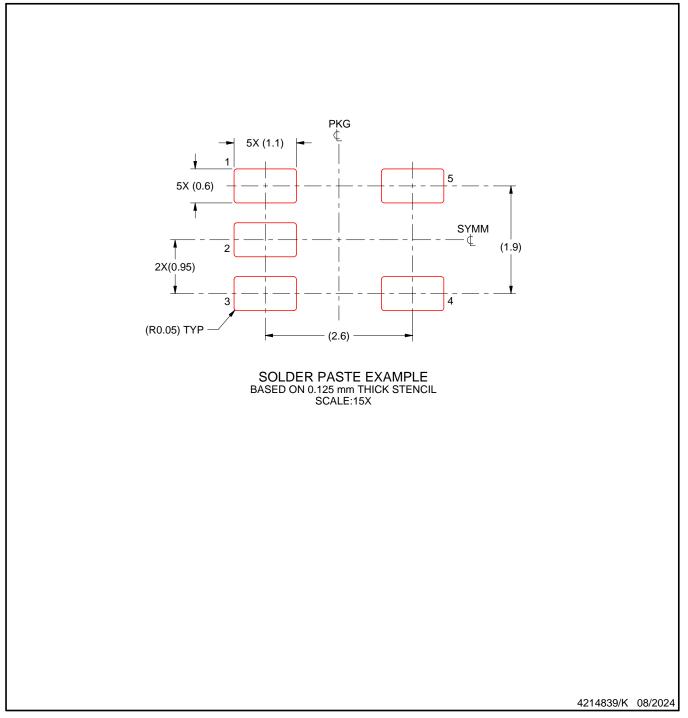


DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated